

## 1550nm DFB Laser Diode, PM Output, up to 30mW (TO39 Package)



### Description:

The PL-DFB-1550-C-A81 1550nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed TO39 package with TEC and PD Built in.

### Features:

- Polarization maintaining (PM) output
- Up to 30 mW output power
- Low RIN noise, -145 dB/Hz maximum
- Narrow linewidth, 2 MHz typ.
- Any Wavelengths to select: from 1210 nm - 2300nm
- Built-in TEC, Thermistor & Monitor PD

### Application:

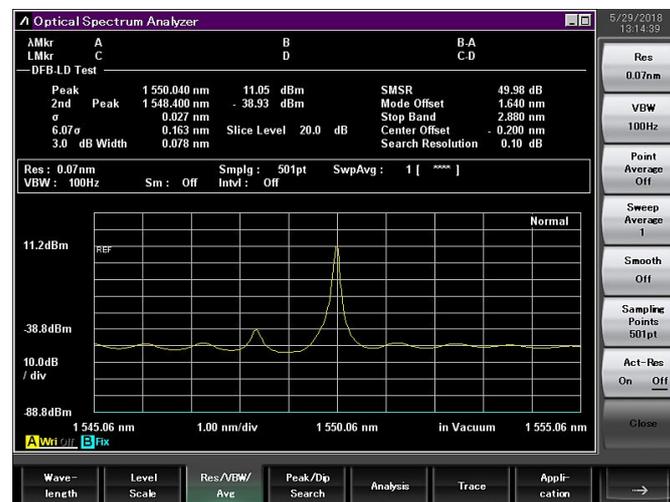
- Dense Wavelength Division Multiplex (DWDM)
- RF over Fiber (RFoF)
- Hybrid Fiber-Coaxial (HFC)
- General laboratory and research use

## Laser Specifications:

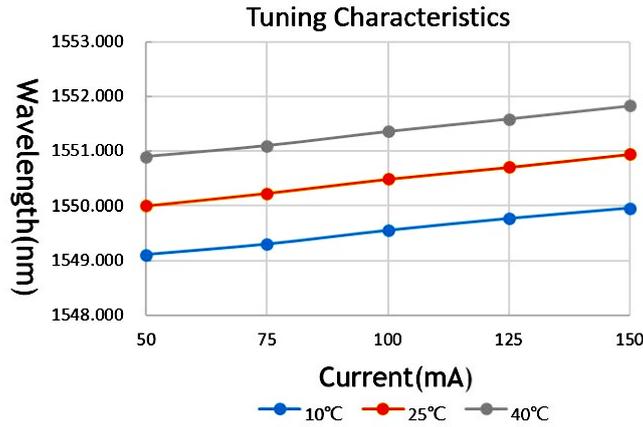
Tsub=25°C, CW bias unless stated otherwise

Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	$\lambda$	1530	1550	1610	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	I <sub>th</sub>		20	30	mA
Operating Current	I <sub>op</sub>		80	120	mA
Chip output Power	P <sub>f</sub>	10	20	35	mW
Quantum Efficiency	$\eta$	0.15	0.25		mW/mA
Current Tuning Coefficient	$\Delta\lambda/\Delta I$		0.015		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda/\Delta T$		0.12		nm/K
Forward Voltage	V <sub>f</sub>		1.3	2	V
Thermistor Resistance	R <sub>T</sub>	9.5	10	10.5	K $\Omega$
Thermistor Temp. Coefficient			-4.4		%/°C
Line width	LW	1	3	10	MHZ
Relative Intensity Noise	RIN	-135	-140	-145	dB/Hz

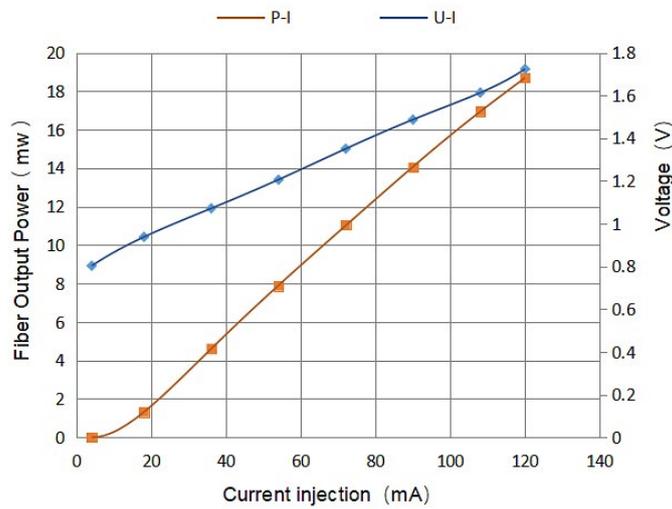
## Spectrum:



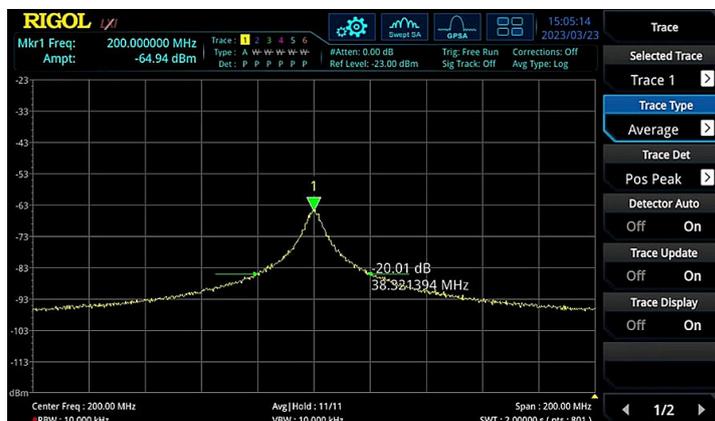
**Tuning Characteristics:**



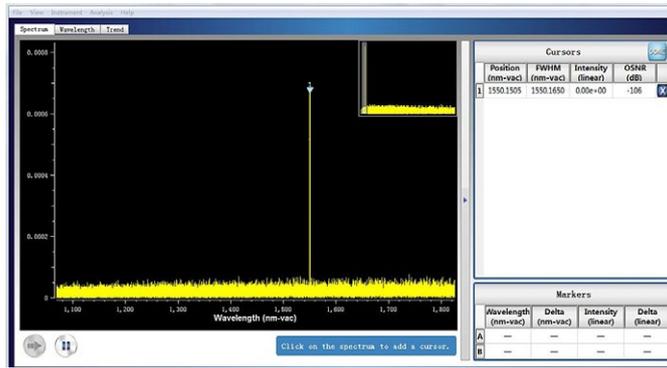
**L-I Curve:**



**DFB Linewidth Testing Result:**

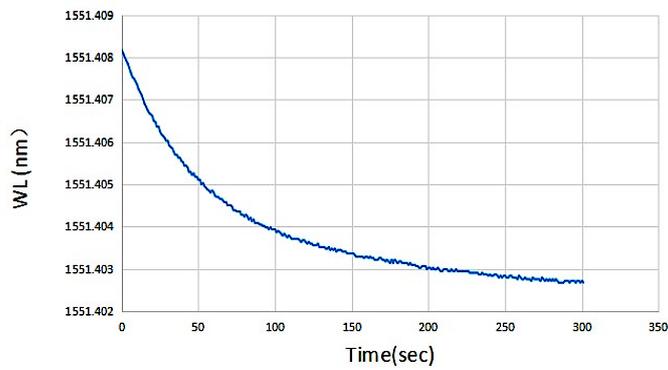


**Central Wavelength:**

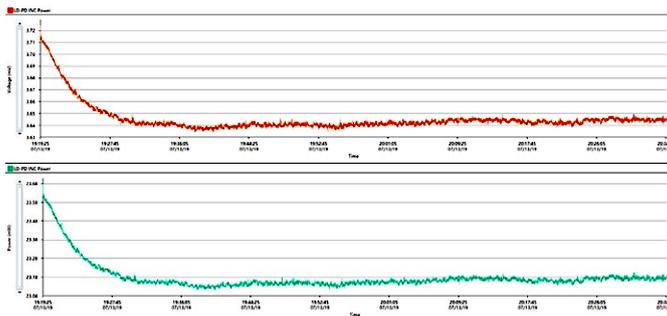


**Wavelength Stability:**

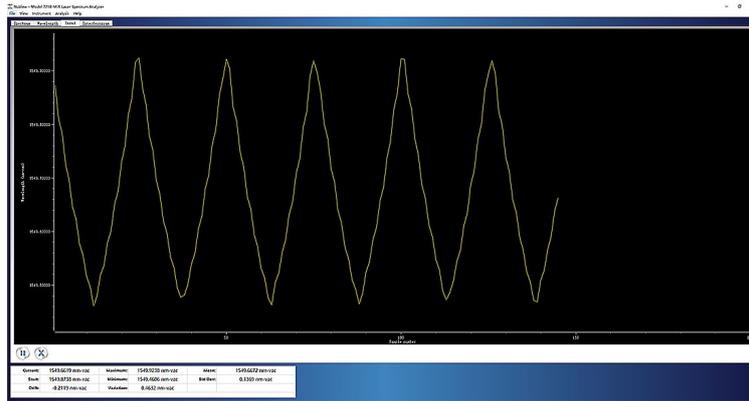
5mins Wavelength stability Test



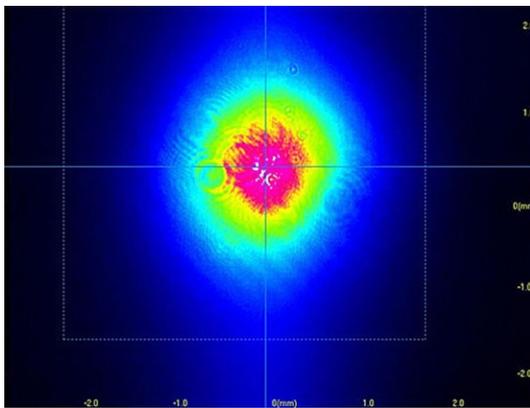
**Power Stability:**



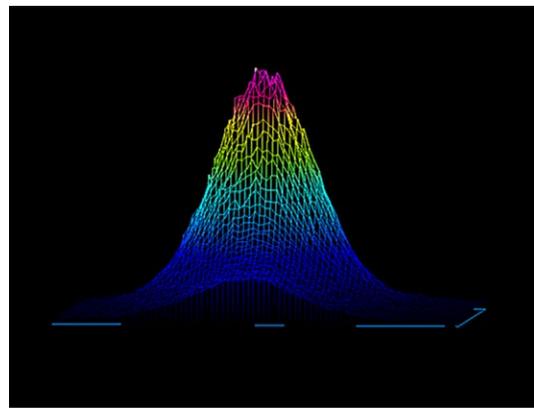
**Mode hoppe tuning Range: 0.46nm:**



**Beam Quality:**

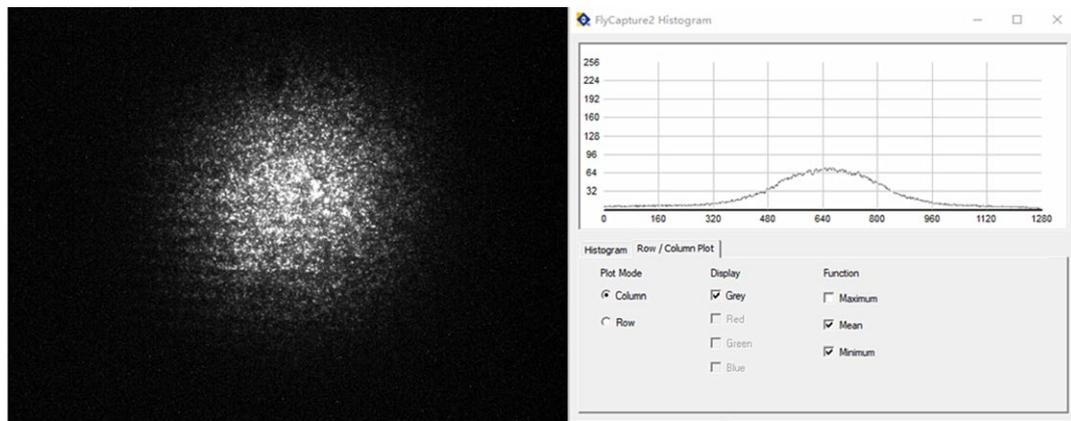


2D

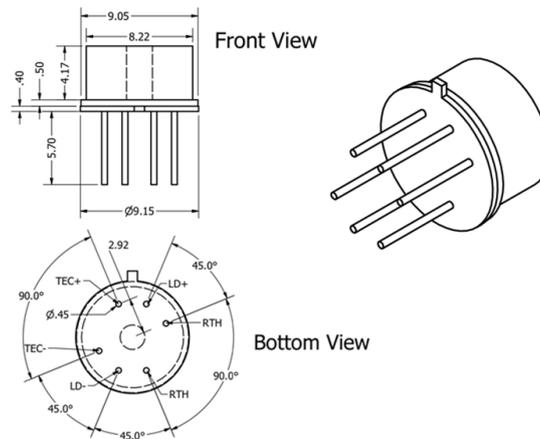


3D

**Camera Analysis:**



**Dimensions and Pin definitions:**



**Absolute Maximum Ratings:**

Item	Unit	Min	Typ	Max
Case Temperature	°C	-5	25	70
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	100	120
Forward Voltage	V	0.8	1.2	1.8
TEC Current	A	-	-	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage (PD)	V	-	-	20

**Ordering Info:**

PL-DFB-□□□□-☆-A8▽-TO39

□□□□: Wavelength

1550: 1550nm

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1653.7: 1653.7nm

☆: Output Power

A: 10mW

B: 20mW

C: 30mw

▽: Wavelength Tolerance

1: ±1nm

2: ±2nm